SCHS278B – APRIL 2003 – REVISED APRIL 2003

••	Operation (CD54HC646) _{CC} Operation (CD74HCT646)	CD74HCT64	6 F PACKAGE 6 M PACKAGE DP VIEW)
 Wide Operating -55°C to 125°C 	Temperature Range of		
Balanced Propa Transition Time	agation Delays and s	SAB [] 2 DIR [] 3	23 CLKBA 22 <u>SB</u> A
 Standard Outpu Loads 	its Drive Up To 15 LS-TTL	A1 [] 4 A2 [] 5	21] OE 20] B1
 Significant Pow LS-TTL Logic IC 	rer Reduction Compared to	A3 [] 6 A4 [] 7 A5 [] 8	19 B2 18 B3 17 B4
 Inputs Are TTL- (CD74HCT646) 	Voltage Compatible	AS [] 8 A6 [] 9 A7 [] 10	16 B5
Independent Re	gisters for A and B Buses	A8 [11	E
Multiplexed Rea	al-Time and Stored Data	GND [12	2 13 B8
True Data Paths	5		

description/ordering information

The CD54HC646 and CD74HCT646 consist of bus-transceiver circuits with 3-state outputs, D-type flip-flops, and control circuitry arranged for multiplexed transmission of data directly from the input bus or from the internal registers. Data on the A or B bus is clocked into the registers on the low-to-high transition of the appropriate clock (CLKAB or CLKBA) input. Figure 1 illustrates the four fundamental bus-management functions that can be performed with these devices.

Output-enable (\overline{OE}) and direction-control (DIR) inputs control the transceiver functions. In the transceiver mode, data present at the high-impedance port can be stored in either or both registers.

The select-control (SAB and SBA) inputs can multiplex stored and real-time (transparent mode) data. DIR determines which bus receives data when \overline{OE} is active (low). In the isolation mode (\overline{OE} high), A data can be stored in one register and/or B data can be stored in the other register.

When an output function is disabled, the input function still is enabled and can be used to store data. Only one of the two buses, A or B, can be driven at a time.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

TA	PAC	KAGE [†]	ORDERABLE PART NUMBER	TOP-SIDE MARKING		
–55°C to 125°C	SOIC – M	Tape and reel	CD74HCT646M96	HCT646M		
-55 C 10 125 C	CDIP – F	Tube	CD54HC646F3A	CD54HC646F3A		

ORDERING INFORMATION

Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



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SCHS278B - APRIL 2003 - REVISED APRIL 2003

					FU	NCTION TABLE		
		INP	UTS			DAT	A I/O	OPERATION OR FUNCTION
OE	DIR	CLKAB	CLKBA	SAB	SBA	A1-A8	B1–B8	OPERATION OR FUNCTION
Х	Х	\uparrow	Х	Х	Х	Input	Unspecified [†]	Store A, B unspecified [†]
х	Х	Х	\uparrow	Х	Х	Unspecified [†]	Input	Store B, A unspecified [†]
Н	Х	\uparrow	\uparrow	Х	Х	Input	Input	Store A and B data
Н	Х	H or L	H or L	Х	Х	Input disabled	Input disabled	Isolation, hold storage
L	L	Х	Х	Х	L	Output	Input	Real-time B data to A bus
L	L	Х	H or L	Х	Н	Output	Input	Stored B data to A bus
L	Н	Х	Х	L	Х	Input	Output	Real-time A data to B bus
L	Н	H or L	Х	Н	Х	Input	Output	Stored A data to B bus

[†] The data-output functions can be enabled or disabled by various signals at OE and DIR. Data-input functions always are enabled; i.e., data at the bus terminals is stored on every low-to-high transition of the clock inputs.





SCHS278B - APRIL 2003 - REVISED APRIL 2003

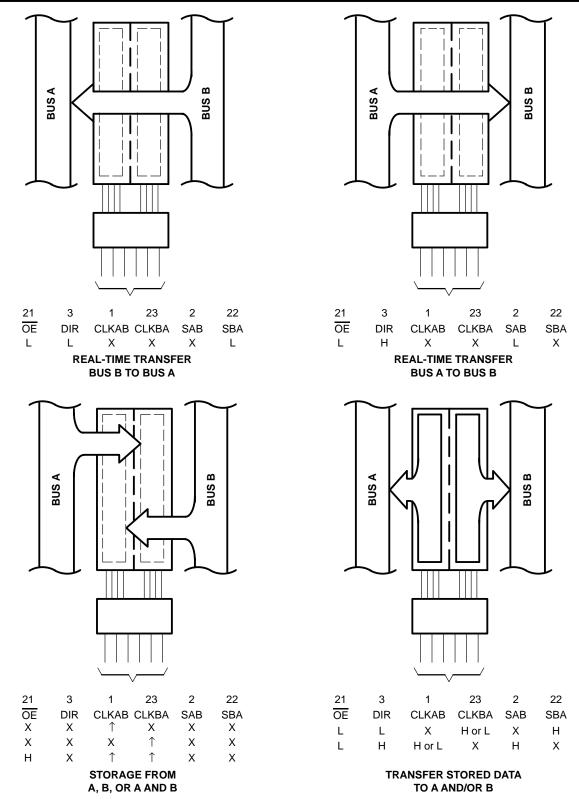
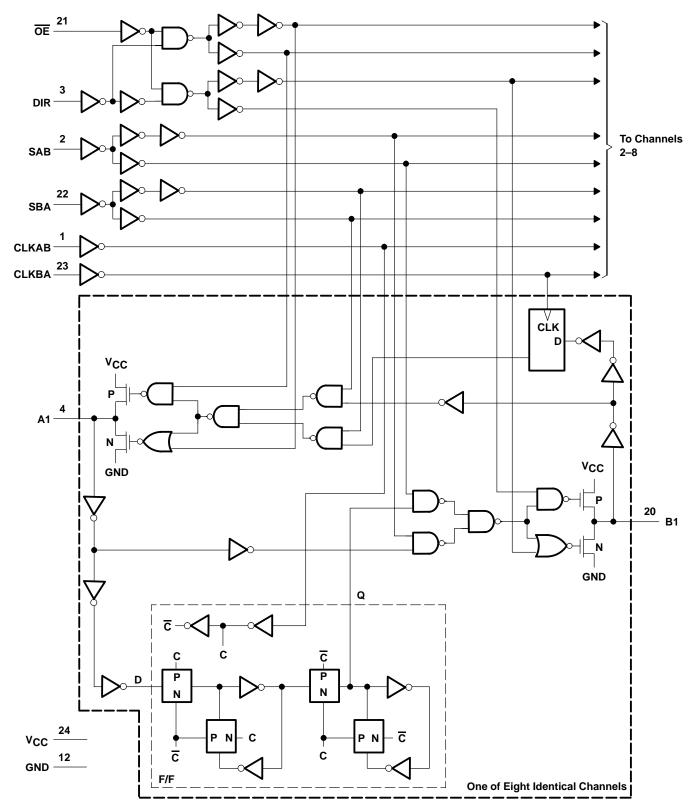


Figure 1. Bus-Management Functions

SCHS278B - APRIL 2003 - REVISED APRIL 2003

logic diagram (positive logic)





SCHS278B - APRIL 2003 - REVISED APRIL 2003

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage range, V _{CC}	–0.5 V to 7 V
Input clamp current, I_{IK} (V _I < 0 or V _I > V _{CC}) (see Note 1)	±20 mA
Output clamp current, I_{OK} (V _O < 0 or V _O > V _{CC}) (see Note 1)	±20 mA
Continuous output drain current per output, $I_O (V_O = 0 \text{ to } V_{CC})$	±35 mA
Continuous current through V _{CC} or GND	
Package thermal impedance, θ_{JA} (see Note 2) M package	46°C/W
Storage temperature range, T _{stg}	–65°C to 150°C

⁺ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

2. The package thermal impedance is calculated in accordance with JESD 51-7.

recommended operating conditions for CD54HC646 (see Note 3)

			MIN	MAX	UNIT
VCC	Supply voltage		2	6	V
		$V_{CC} = 2 V$	1.5		
VIH	High-level input voltage	V_{CC} = 4.5 V	3.15		V
		$V_{CC} = 6 V$	4.2		
		$V_{CC} = 2 V$		0.5	
VIL	Low-level input voltage	V_{CC} = 4.5 V		1.35	V
		VCC = 6 V		1.8	
VI	Input voltage		0	VCC	V
٧o	Output voltage		0	VCC	V
		$V_{CC} = 2 V$		1000	
tt	Input transition (rise and fall) time	$V_{CC} = 4.5 V$		500	ns
		VCC = 6 V		400	
ТА	Operating free-air temperature		-55	125	°C

NOTE 3: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

recommended operating conditions for CD74HCT646 (see Note 3)

		MIN	MAX	UNIT
VCC	Supply voltage	4.5	5.5	V
VIH	High-level input voltage	2		V
V_{IL}	Low-level input voltage		0.8	V
VI	Input voltage		VCC	V
Vo	Output voltage		VCC	V
tt	Input transition (rise and fall) time		500	ns
Τ _Α	Operating free-air temperature	-55	125	°C

NOTE 4: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



SCHS278B - APRIL 2003 - REVISED APRIL 2003

electrical characteristics for CD54HC646 over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS		Vcc	T _A = 25°C		T _A = −55°C TO 125°C		T _A = −40°C TO 85°C		UNIT
				MIN	MAX	MIN	MAX	MIN	MAX	
			2 V	1.9		1.9		1.9		
		I _{OH} = -20 μA	4.5 V	4.4		4.4		4.4		
VOH	$V_I = V_{IH} \text{ or } V_{IL}$		6 V	5.9		5.9		5.9		V
		I _{OH} = -6 mA	4.5 V	3.98		3.7		3.84		
		I _{OH} = -7.8 mA	6 V	5.48		5.2		5.34		
	VI = VIH or VIL	I _{OL} = 20 μA	2 V		0.1		0.1		0.1	
			4.5 V		0.1		0.1		0.1	
V _{OL}			6 V		0.1		0.1		0.1	V
		I _{OL} = 6 mA	4.5 V		0.26		0.4		0.33	
		I _{OL} = 7.8 mA	6 V		0.26		0.4		0.33	
Ц	$V_{I} = V_{CC} \text{ or } 0$		6 V		±0.1		±1		±1	μA
I _{OZ}	AO = ACC or 0		6 V		±0.5		±10		±5	μA
ICC	$V_I = V_{CC} \text{ or } 0,$	IO = 0	6 V		8		160		80	μA
Ci					10		10		10	pF
Co					20		20		20	pF

electrical characteristics for CD74HCT646 over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CON	Vcc	т,	ק = 25°C	;	T _A = - TO 12		T _A = −40°C TO 85°C		UNIT		
				MIN	TYP	MAX	MIN	MAX	MIN	MAX		
Vou	VI = VIH or VIL	I _{OH} = -20 μA	4.5 V	4.4			4.4		4.4		v	
VOH	VI = VIH OI VIL	I _{OH} = -6 mA	4.5 V	3.98			3.7		3.84		v	
Ve	$V_{I} = V_{IH} \text{ or } V_{IL}$ $I_{OL} = 20 \mu\text{A}$		4.5 V			0.1		0.1		0.1	V	
VOL		I _{OL} = 6 mA	4.5 V			0.26		0.4		0.33	v	
lį	$V_I = V_{CC}$ to GND		5.5 V			±0.1		±1		±1	μΑ	
loz	VO = ACC or 0		5.5 V			±0.5		±10		±5	μΑ	
ICC	$V_I = V_{CC} \text{ or } 0,$	IO = 0	5.5 V			8		160		80	μΑ	
∆lCC‡	One input at V_{CC} – 2.1 V, Other inputs at 0 or V_{CC}		4.5 V to 5.5 V		100	360		490		450	μΑ	
Ci						10		10		10	pF	
Co						20		20		20	pF	

[†] Additional quiescent supply current per input pin, TTL inputs high, 1 unit load



SCHS278B - APRIL 2003 - REVISED APRIL 2003

HOT IN OT EOAD	
INPUT	UNIT LOAD [†]
OE	1.3
DIR	0.75
CLKAB or CLKBA	0.6
SAB or SBA	0.45
A or B	0.3

HCT INPUT LOADING TABLE

[†]Unit Load is ΔI_{CC} limit specified in electrical characteristics table (e.g., 360 μA max at 25°C).

timing requirements for CD54HC646 over recommended operating free-air temperature range (unless otherwise noted) (see Figure 2)

		vcc	T _A = 25°C		T _A = −55°C TO 125°C		T _A = −40°C TO 85°C		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	
		2 V		6		4		5	
fclock	Clock frequency	4.5 V		30		20		25	MHz
		6 V		35		23		29	
	Pulse duration, CLKBA or CLKAB high or low	2 V	80		120		100		
tw		4.5 V	16		24		20		ns
		6 V	14		20		17		
		2 V	60		90		75		
t _{su}	Setup time, A before CLKAB \uparrow or B before CLKBA \uparrow	4.5 V	12		18		15		ns
		6 V	10		15		13		
	Hold time, A after CLKAB↑ or B after CLKBA↑	2 V	35		55		45		ns
^t h		4.5 V	7		11		9		
		6 V	6		9		8		

timing requirements for CD74HCT646 over recommended operating free-air temperature range, $V_{CC} = 4.5 \text{ V}$ (unless otherwise noted) (see Figure 3)

		T _A = 25°C		T _A = - TO 12	-55°C 25°C	T _A = −40°C TO 85°C		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	
fclock	Clock frequency		25		17		20	MHz
tw	Pulse duration, CLKBA or CLKAB high or low	25		38		31		ns
t _{su}	Setup time, A before CLKAB \uparrow or B before CLKBA \uparrow	12		18		15		ns
t _h	Hold time, A after CLKAB↑ or B after CLKBA↑	5		5		5		ns



SCHS278B - APRIL 2003 - REVISED APRIL 2003

switching characteristics for CD54HC646 over recommended operating free-air temperature range (unless otherwise noted) (see Figure 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	vcc	T,	A = 25°C	;	T _A = - TO 12	-55°C 25°C	T _A = - TO 8		UNIT		
			CAPACITANCE		MIN	TYP	MAX	MIN	MAX	MIN	MAX			
				2 V	6			4		5				
f			C _L = 50 pF	4.5 V	30			20		25		MHz		
fmax				6 V	35			23		29				
			C _L = 15 pF	5 V		60								
				2 V			220		330		275			
	CLKBA or	A or B	CL = 50 pF	4.5 V			44		66		55			
	CLKAB	AUB		6 V			37		56		47			
			CL = 15 pF	5 V		18								
				2 V			135		205		170			
^t pd	A or B	B B or A	C _L = 50 pF	4.5 V			27		41		34	34 29		
	AUD	BUIA		6 V			23		35		29			
			CL = 15 pF	5 V		12								
	SBA or SAB†			2 V			170		255		215	;		
			A or D	CL = 50 pF	4.5 V			34		51		43		
		A or B		6 V			29		43		37			
			C _L = 15 pF	5 V		14								
				2 V			175		265		220			
	OE	A an D	C _L = 50 pF	4.5 V			35		53		44			
ten	UE	A or B		6 V			30		45		37	ns		
			CL = 15 pF	5 V		14								
				2 V			175		265		220			
	OE	A D	C _L = 50 pF	4.5 V			35		53		44			
^t dis	ÛE	A or B		6 V			30		45		37	ns		
			C _L = 15 pF	5 V		14								
				2 V			60		90		75			
tt		Any	C _L = 50 pF	C _L = 50 pF 4		4.5 V			12		18		15	ns
				6 V			10		15		13			

[†] These parameters are measured with the internal output state of the storage register opposite that of the bus input.



SCHS278B - APRIL 2003 - REVISED APRIL 2003

switching characteristics for CD74HCT646 over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	Vcc	T _A = 25°C			T _A = −55°C TO 125°C		T _A = −40°C TO 85°C		UNIT								
	(INFUT)	(001-01)	CAFACITANCE		MIN	TYP	MAX	MIN	MAX	MIN	MAX									
4			CL = 50 pF	4.5 V	25			17		20		MHz								
f _{max}			CL = 15 pF	5 V		45														
	CLKBA or	A or B	C _L = 50 pF	4.5 V			44		66		55	5								
	CLKAB	AUB	C _L = 15 pF	5 V		18														
÷.	A or B	B or A	C _L = 50 pF 4.5 V 37	56		46	ns													
^t pd		BUIA	C _L = 15 pF	5 V		15						115								
	SBA or SAB†	A or B	CL = 50 pF	4.5 V			46	69	69		58									
		AUD	CL = 15 pF	5 V		19														
	ŌĒ		~						05	A or B	C _L = 50 pF	4.5 V			45		68		56	ns
^t en		AUID	AUD	AUD	AUD	A OF B	A OF B	A OF B	A OF B	C _L = 15 pF	5 V		19						115	
^t dis	OE	A or B	C _L = 50 pF	4.5 V			35		53		44									
		AUD	C _L = 15 pF	5 V		14						ns								
tt			C _L = 50 pF	4.5 V			12		18		15	ns								

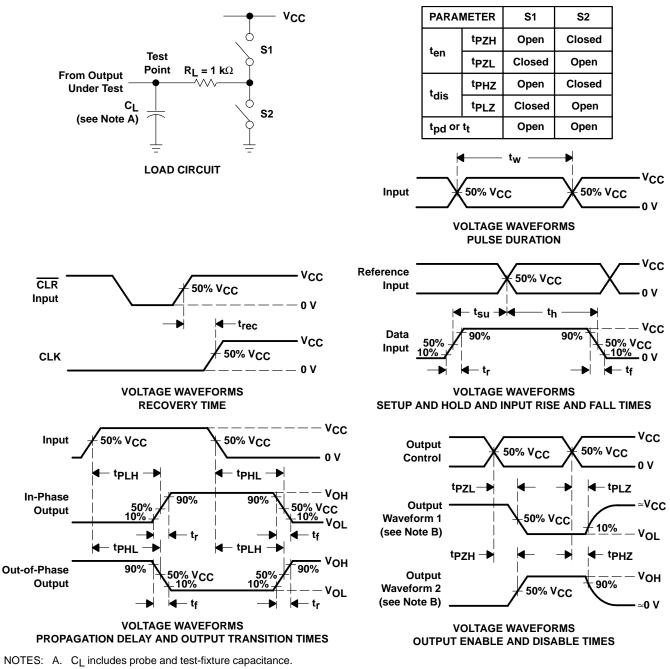
[†] These parameters are measured with the internal output state of the storage register opposite that of the bus input.

operating characteristics, V_{CC} = 5 V, T_A = 25° C

PARAMETER			
C _{pd} Power dissipation capacitance	52	pF	

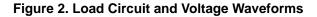


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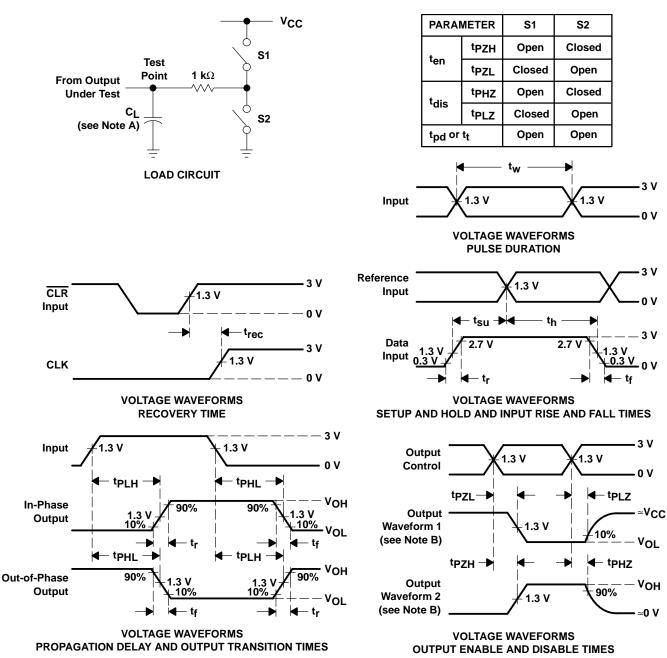
PARAMETER MEASUREMENT INFORMATION – CD54HC646

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, Z_O = 50 Ω , t_r = 6 ns.
- D. For clock inputs, fmax is measured with the input duty cycle at 50%.
- E. The outputs are measured one at a time with one input transition per measurement.
- F. tpLz and tpHz are the same as tdis.
- G. tpzL and tpzH are the same as ten.
- H. tpLH and tpHL are the same as tpd.



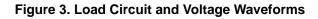


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PARAMETER MEASUREMENT INFORMATION – CD74HCT646

- NOTES: A. CL includes probe and test-fixture capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control.
 Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 C. Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following
 - characteristics: PRR \leq 1 MHz, Z_O = 50 Ω , t_r = 6 ns. t_f = 6 ns.
 - D. For clock inputs, f_{max} is measured with the input duty cycle at 50%.
 - E. The outputs are measured one at a time with one input transition per measurement.
 - F. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
 - G. t_{PZL} and t_{PZH} are the same as t_{en} .
 - H. tpLH and tpHL are the same as t_{pd} .







10-Dec-2020

PACKAGING INFORMATION

Orderable Device	Status	Package Type		Pins	-	Eco Plan	Lead finish/	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	Ball material	(3)		(4/5)	
							(6)				
5962-8688501JA	ACTIVE	CDIP	J	24	1	Non-RoHS & Non-Green	Call TI	N / A for Pkg Type	-55 to 125	5962-8688501JA CD54HC646F3A	Samples
CD54HC646F3A	ACTIVE	CDIP	J	24	1	Non-RoHS & Non-Green	Call TI	N / A for Pkg Type	-55 to 125	5962-8688501JA CD54HC646F3A	Samples
CD74HCT646M96	ACTIVE	SOIC	DW	24	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT646M	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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10-Dec-2020

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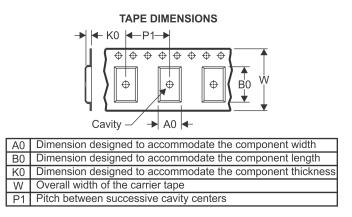
PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74HCT646M96	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1

TEXAS INSTRUMENTS

www.ti.com

PACKAGE MATERIALS INFORMATION

14-Feb-2019



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins SPQ		Length (mm)	Width (mm)	Height (mm)	
CD74HCT646M96	SOIC	DW	24	2000	350.0	350.0	43.0	

DW (R-PDSO-G24)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-013 variation AD.



MECHANICAL DATA

MCDI004A - JANUARY 1995 - REVISED NOVEMBER 1997

CERAMIC DUAL-IN-LINE PACKAGE

J (R-GDIP-T**)



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. Window (lens) added to this group of packages (24-, 28-, 32-, 40-pin).
- D. This package can be hermetically sealed with a ceramic lid using glass frit.
- E. Index point is provided on cap for terminal identification.



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